

TS5A23166 0.9-Ω Dual-SPST Analog Switch 5-V and 3.3-V 2-Channel Analog Switch

1 Features

- Isolation in Powered-Down Mode, $V_+ = 0$
- Low ON-state resistance (0.9 Ω)
- Control inputs are 5.5-V Tolerant
- Low charge injection
- Excellent ON-state resistance matching
- Low total harmonic distortion (THD)
- 1.65-V to 5.5-V Single-supply operation
- Latch-up performance exceeds 100 mA per JESD 78, class II
- ESD Performance tested per JESD 22
 - 2000-V Human-body model (A114-B, Class II)
 - 1000-V Charged-device model (C101)

2 Applications

- [Cell phones](#)
- [Portable instrumentation](#)
- [Audio and video signal routing](#)
- [Low-voltage data-acquisition systems](#)
- [Communication circuits](#)
- [Modems](#)
- [Hard Drives](#)
- [Computer Peripherals](#)
- [Wireless Terminals and Peripherals](#)

3 Description

The TS5A23166 device is a dual single-pole single-throw (SPST) analog switch that is designed to operate from 1.65 V to 5.5 V. The TS5A23166 device offers a low ON-state resistance and an excellent channel-to-channel ON-state resistance matching. The TS5A23166 device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|-----------|-------------------|
| TS5A23166 | VSSOP (8) | 2.30 mm × 2.00 mm |
| | DSBGA (8) | 1.91 mm × 0.91 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

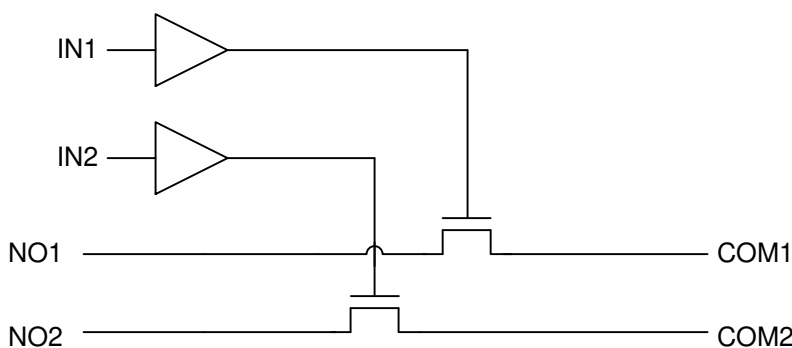


Table of Contents

| | | | | | |
|----------|--|-----------|-----------|---|-----------|
| 1 | Features | 1 | 8 | Detailed Description | 18 |
| 2 | Applications | 1 | 8.1 | Overview | 18 |
| 3 | Description | 1 | 8.2 | Functional Block Diagram | 18 |
| 4 | Revision History | 2 | 8.3 | Feature Description | 18 |
| 5 | Pin Configuration and Functions | 3 | 8.4 | Device Functional Modes | 18 |
| 6 | Specifications | 3 | 9 | Application and Implementation | 19 |
| 6.1 | Absolute Maximum Ratings | 3 | 9.1 | Application Information | 19 |
| 6.2 | ESD Ratings | 4 | 9.2 | Typical Application | 19 |
| 6.3 | Recommended Operating Conditions | 4 | 10 | Power Supply Recommendations | 20 |
| 6.4 | Thermal Information | 4 | 11 | Layout | 20 |
| 6.5 | Electrical Characteristics: 5-V Supply | 4 | 11.1 | Layout Guidelines | 20 |
| 6.6 | Electrical Characteristics: 3.3-V Supply | 6 | 11.2 | Layout Example | 20 |
| 6.7 | Electrical Characteristics: 2.5-V Supply | 7 | 12 | Device and Documentation Support | 21 |
| 6.8 | Electrical Characteristics: 1.8-V Supply | 9 | 12.1 | Device Support | 21 |
| 6.9 | Switching Characteristics: 5-V Supply | 10 | 12.2 | Receiving Notification of Documentation Updates | 22 |
| 6.10 | Switching Characteristics: 3.3-V Supply | 10 | 12.3 | Community Resources | 22 |
| 6.11 | Switching Characteristics: 2.5-V Supply | 10 | 12.4 | Trademarks | 22 |
| 6.12 | Switching Characteristics: 1.8-V Supply | 11 | 12.5 | Electrostatic Discharge Caution | 22 |
| 6.13 | Typical Characteristics | 12 | 12.6 | Glossary | 22 |
| 7 | Parameter Measurement Information | 14 | 13 | Mechanical, Packaging, and Orderable Information | 22 |

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision I (March 2018) to Revision J Page

- Changed the *Thermal Information* table

4

Changes from Revision H (May 2015) to Revision I Page

- Added Note: "Not tested in production" to leakage current at 25°C in the *Electrical Characteristics* tables

4

Changes from Revision G (February 2013) to Revision H Page

- Added *Pin Configuration and Functions* section, *ESD Ratings* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section
- Updated document to new TI data sheet format - no specification changes.
- Removed *Ordering Information* table.

1

1

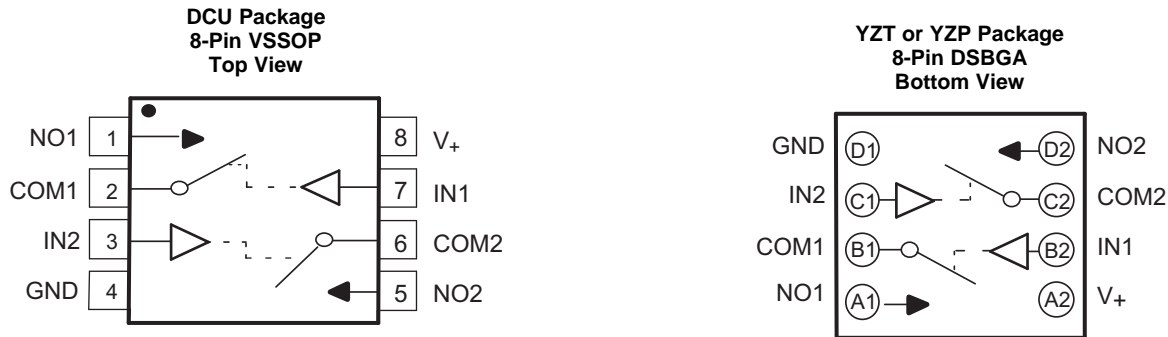
1

Changes from Revision F (September 2012) to Revision G Page

- Changed pin numbers for YZT or YZP package pinout.

3

5 Pin Configuration and Functions



Pin Functions

| PIN | | | TYPE | DESCRIPTION |
|------|-----------|-----------|------|---|
| NAME | TSSOP NO. | DSBGA NO. | | |
| COM1 | 2 | B1 | I/O | Common port for switch 1 |
| COM2 | 6 | C2 | I/O | Common port for switch 2 |
| GND | 4 | D1 | GND | Ground |
| IN1 | 7 | B2 | I | Active-high control pin connecting NO1 to COM1. |
| IN2 | 3 | C1 | I | Active-high control pin connecting NO2 to COM2. |
| NO1 | 1 | A1 | I/O | Normally open switch path 1 |
| NO2 | 5 | D2 | I/O | Normally open switch path 2 |
| V+ | 8 | A2 | PWR | Power supply pin |

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

| | | MIN | MAX | UNIT |
|-------------------------------------|---|--|----------------------|------|
| V ₊ | Supply voltage ⁽³⁾ | -0.5 | 6.5 | V |
| V _{NO} V _{COM} | Analog voltage ⁽³⁾⁽⁴⁾⁽⁵⁾ | -0.5 | V ₊ + 0.5 | V |
| I _K | Analog port diode current | V _{NO} , V _{COM} < 0 | | mA |
| I _{NO} | ON-state switch current | V _{NO} , V _{COM} = 0 to V ₊ | | mA |
| I _{COM} | ON-state peak switch current ⁽⁶⁾ | V _{NO} , V _{COM} = 0 to V ₊ | | mA |
| V _I | Digital input voltage ⁽³⁾⁽⁴⁾ | -0.5 | 6.5 | V |
| I _{IK} | Digital input clamp current | V _I < 0 | | mA |
| I ₊ | Continuous current through V ₊ | | 100 | mA |
| I _{GND} | Continuous current through GND | -100 | 100 | mA |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.
- (6) Pulse at 1-ms duration < 10% duty cycle.

6.2 ESD Ratings

| | | VALUE | UNIT |
|-------------------------------------|--|-------|------|
| $V_{(ESD)}$ Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | +2000 | V |
| | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | +1000 | |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|-----------|--------------------------------|------|-------|------|
| $V_{I/O}$ | Input/output voltage | 0 | V_+ | V |
| V_+ | Supply voltage | 1.65 | 5.5 | V |
| V_I | Control Input Voltage | 0 | 5.5 | V |
| T_A | Operating free-air temperature | -40 | 85 | °C |

6.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | TS5A23166 | | | UNIT |
|--|-------------|-------------|-------------|------|
| | DCU (VSSOP) | YZP (DSBGA) | YZT (DSBGA) | |
| | 8 PINS | 8 PINS | 8 PINS | |
| $R_{\theta JA}$ Junction-to-ambient thermal resistance | 212.2 | 99.9 | 99.7 | °C/W |
| $R_{\theta JC(top)}$ Junction-to-case (top) thermal resistance | 77.6 | 1.0 | 1.4 | °C/W |
| $R_{\theta JB}$ Junction-to-board thermal resistance | 91.7 | 27.8 | 27.8 | °C/W |
| ϕ_{JT} Junction-to-top characterization parameter | 7.1 | 0.4 | 0.5 | °C/W |
| ϕ_{JB} Junction-to-board characterization parameter | 91.1 | 27.8 | 27.7 | °C/W |

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics: 5-V Supply

$V_+ = 4.5\text{ V to }5.5\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | TEST CONDITIONS | T_A | V_+ | MIN | TYP | MAX | UNIT | |
|----------------------|--|--|-------|-------|------|-------|-------------------|---------------|
| Analog Switch | | | | | | | | |
| V_{COM}, V_{NO} | Analog signal | | | 0 | | V_+ | V | |
| r_{peak} | Peak ON resistance | $0 \leq V_{NO} \leq V_+$, $I_{COM} = -100\text{ mA}$, Switch ON, see Figure 11 | 25°C | 4.5 V | 0.9 | 1.1 | Ω | |
| | | | Full | | 1.2 | | | |
| r_{on} | ON-state resistance | $V_{NO} = 2.5\text{ V}$, $I_{COM} = -100\text{ mA}$, Switch ON, see Figure 11 | 25°C | 4.5 V | 0.75 | 0.9 | Ω | |
| | | | Full | | 1 | | | |
| Δr_{on} | ON-state resistance match between channels | $V_{NO} = 2.5\text{ V}$, $I_{COM} = -100\text{ mA}$, Switch ON, see Figure 11 | 25°C | 4.5 V | 0.04 | 0.1 | Ω | |
| | | | Full | | 0.1 | | | |
| $r_{on(flat)}$ | ON-state resistance flatness | $0 \leq V_{NO} \leq V_+$, $I_{COM} = -100\text{ mA}$, Switch ON, see Figure 11 | 25°C | 4.5 V | 0.2 | | Ω | |
| | | | 25°C | | 0.15 | 0.25 | | |
| | | | Full | | 0.25 | | | |
| $I_{NO(OFF)}$ | NO OFF leakage current | $V_{NO} = 1\text{ V}$, $V_{COM} = 4.5\text{ V}$, or $V_{NO} = 4.5\text{ V}$, $V_{COM} = 1\text{ V}$, Switch OFF, see Figure 12 | 25°C | 5.5 V | 0 V | 4 | 20 ⁽²⁾ | nA |
| | | | Full | | -150 | 150 | | |
| $I_{NO(PWROFF)}$ | | $V_{NO} = 0\text{ to }5.5\text{ V}$, $V_{COM} = 5.5\text{ V to }0$, Switch OFF, see Figure 12 | 25°C | 0 V | -10 | 0.2 | 10 ⁽²⁾ | μA |
| | | | Full | | -50 | 50 | | |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(2) Not tested in production.

Electrical Characteristics: 5-V Supply (continued)
 $V_+ = 4.5 \text{ V to } 5.5 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT |
|--|------------------------------|--|---|-------|-------|------|--------|-------------------|------|
| $I_{\text{COM(OFF)}}$ | COM OFF leakage current | $V_{\text{COM}} = 1 \text{ V}$, $V_{\text{NO}} = 4.5 \text{ V}$, or $V_{\text{COM}} = 4.5 \text{ V}$, $V_{\text{NO}} = 1 \text{ V}$, | Switch OFF, see Figure 12 | 25°C | 5.5 V | 0 V | 4 | 20 ⁽²⁾ | nA |
| | | | | Full | | -150 | 150 | | |
| $I_{\text{COM(PWROFF)}}$ | | $V_{\text{COM}} = 0 \text{ to } 5.5 \text{ V}$, $V_{\text{NO}} = 5.5 \text{ V to } 0$, | Switch OFF, see Figure 12 | 25°C | 0 V | -10 | 0.2 | 10 ⁽²⁾ | μA |
| | | | | Full | | -50 | 50 | | |
| $I_{\text{NO(ON)}}$ | NO ON leakage current | $V_{\text{NO}} = 1 \text{ V}$, $V_{\text{COM}} = \text{Open}$, or $V_{\text{NO}} = 4.5 \text{ V}$, $V_{\text{COM}} = \text{Open}$, | Switch ON, see Figure 13 | 25°C | 5.5 V | -5 | 0.4 | 5 ⁽²⁾ | nA |
| | | | | Full | | -50 | 50 | | |
| $I_{\text{COM(ON)}}$ | COM ON leakage current | $V_{\text{COM}} = 1 \text{ V}$, $V_{\text{NO}} = \text{Open}$, or $V_{\text{COM}} = 4.5 \text{ V}$, $V_{\text{NO}} = \text{Open}$, | Switch ON, see Figure 13 | 25°C | 5.5 V | -5 | 0.4 | 5 ⁽²⁾ | nA |
| | | | | Full | | -50 | 50 | | |
| Digital Control Inputs (IN1, IN2)⁽³⁾ | | | | | | | | | |
| V_{IH} | Input logic high | | | Full | | 2.4 | | 5.5 | V |
| V_{IL} | Input logic low | | | Full | | 0 | | 0.8 | V |
| $I_{\text{IH}}, I_{\text{IL}}$ | Input leakage current | $V_1 = 5.5 \text{ V or } 0$ | | 25°C | 5.5 V | -2 | 0.3 | 2 | nA |
| | | | | Full | | -20 | 20 | | |
| Dynamic | | | | | | | | | |
| Q_C | Charge injection | $V_{\text{GEN}} = 0$, $R_{\text{GEN}} = 0$, | $C_L = 1 \text{ nF}$, see Figure 19 | 25°C | 5 V | | 6 | | pC |
| $C_{\text{NO(OFF)}}$ | NO OFF capacitance | $V_{\text{NO}} = V_+ \text{ or GND}$, Switch OFF, | See Figure 14 | 25°C | 5 V | | 19 | | pF |
| $C_{\text{COM(OFF)}}$ | COM OFF capacitance | $V_{\text{COM}} = V_+ \text{ or GND}$, Switch OFF, | See Figure 14 | 25°C | 5 V | | 18 | | pF |
| $C_{\text{NO(ON)}}$ | NO ON capacitance | $V_{\text{NO}} = V_+ \text{ or GND}$, Switch ON, | See Figure 14 | 25°C | 5 V | | 35.5 | | pF |
| $C_{\text{COM(ON)}}$ | COM ON capacitance | $V_{\text{COM}} = V_+ \text{ or GND}$, Switch ON, | See Figure 14 | 25°C | 5 V | | 35.5 | | pF |
| C_I | Digital input capacitance | $V_1 = V_+ \text{ or GND}$, | See Figure 14 | 25°C | 5 V | | 2 | | pF |
| BW | Bandwidth | $R_L = 50 \Omega$, Switch ON, | See Figure 16 | 25°C | 5 V | | 150 | | MHz |
| O_{ISO} | OFF isolation | $R_L = 50 \Omega$, $f = 1 \text{ MHz}$, | Switch OFF, see Figure 17 | 25°C | 5 V | | -62 | | dB |
| X_{TALK} | Crosstalk | $R_L = 50 \Omega$, $f = 1 \text{ MHz}$, | Switch ON, see Figure 18 | 25°C | 5 V | | -85 | | dB |
| THD | Total harmonic distortion | $R_L = 600 \Omega$, $C_L = 50 \text{ pF}$, | $f = 20 \text{ Hz to } 20 \text{ kHz}$, see Figure 20 | 25°C | 5 V | | 0.005% | | |
| Supply | | | | | | | | | |
| I_+ | Positive supply current | $V_1 = V_+ \text{ or GND}$, | Switch ON or OFF | 25°C | 5.5 V | | 0.01 | 0.1 | μA |
| | | | | Full | | | 1 | | |

(3) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

6.6 Electrical Characteristics: 3.3-V Supply

 $V_+ = 3\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT | |
|--|--|--|--|--------------|-------|-----|--------------|------------------|------------------|---------------|
| Analog Switch | | | | | | | | | | |
| $V_{\text{COM}}, V_{\text{NO}}$ | Analog signal range | | | | | 0 | | V_+ | V | |
| r_{peak} | Peak ON resistance | $0 \leq V_{\text{NO}} \leq V_+$, $I_{\text{COM}} = -100\text{ mA}$, | Switch ON, see Figure 11 | 25°C Full | 3 V | | 1.3 1.6 | 1.8 | Ω | |
| r_{on} | ON-state resistance | $V_{\text{NO}} = 2\text{ V}$, $I_{\text{COM}} = -100\text{ mA}$, | Switch ON, see Figure 11 | 25°C Full | 3 V | | 1.1 1.5 | 1.7 | Ω | |
| Δr_{on} | ON-state resistance match between channels | $V_{\text{NO}} = 2\text{ V}$, 0.8 V, $I_{\text{COM}} = -100\text{ mA}$, | Switch ON, see Figure 11 | 25°C Full | 3 V | | 0.04 0.1 | 0.1 | Ω | |
| $r_{\text{on(flat)}}$ | ON-state resistance flatness | $0 \leq V_{\text{NO}} \leq V_+$, $I_{\text{COM}} = -100\text{ mA}$ | Switch ON, see Figure 11 | 25°C | 3 V | | 0.3 | | Ω | |
| | | $V_{\text{NO}} = 2\text{ V}$, 0.8 V, $I_{\text{COM}} = -100\text{ mA}$, | Switch ON, see Figure 11 | 25°C Full | | | 0.15 0.25 | 0.25 | | |
| | | | | | | | | | | |
| $I_{\text{NO(OFF)}}$ | NO OFF leakage current | $V_{\text{NO}} = 1\text{ V}$, $V_{\text{COM}} = 3\text{ V}$, or $V_{\text{NO}} = 3\text{ V}$, $V_{\text{COM}} = 1\text{ V}$, | Switch OFF, see Figure 12 | 25°C | 3.6 V | | -5 | 0.5 | 5 ⁽²⁾ | nA |
| | | | | Full | | | -50 | 50 | | |
| $I_{\text{NO(PWROFF)}}$ | | $V_{\text{NO}} = 0\text{ to }3.6\text{ V}$, $V_{\text{COM}} = 3.6\text{ V to }0$, | Switch OFF, see Figure 12 | 25°C | 0 V | | -5 | 0.1 | 5 ⁽²⁾ | μA |
| | | | | Full | | | -25 | 25 | | |
| $I_{\text{COM(OFF)}}$ | COM OFF leakage current | $V_{\text{COM}} = 1\text{ V}$, $V_{\text{NO}} = 3\text{ V}$, or $V_{\text{COM}} = 3\text{ V}$, $V_{\text{NO}} = 1\text{ V}$, | Switch OFF, see Figure 12 | 25°C | 3.6 V | | -5 | 0.5 | 5 ⁽²⁾ | nA |
| | | | | Full | | | -50 | 50 | | |
| $I_{\text{COM(PWROFF)}}$ | | $V_{\text{COM}} = 0\text{ to }3.6\text{ V}$, $V_{\text{NO}} = 3.6\text{ V to }0$, | Switch OFF, see Figure 12 | 25°C | 0 V | | -5 | 0.1 | 5 ⁽²⁾ | μA |
| | | | | Full | | | -25 | 25 | | |
| $I_{\text{NO(ON)}}$ | NO ON leakage current | $V_{\text{NO}} = 1\text{ V}$, $V_{\text{COM}} = \text{Open}$, or $V_{\text{NO}} = 3\text{ V}$, $V_{\text{COM}} = \text{Open}$, | Switch ON, see Figure 13 | 25°C Full | 3.6 V | | -2 0.3 | 2 ⁽²⁾ | nA | |
| | | | | | | | | -20 | | 20 |
| $I_{\text{COM(ON)}}$ | COM ON leakage current | $V_{\text{COM}} = 1\text{ V}$, $V_{\text{NO}} = \text{Open}$, or $V_{\text{COM}} = 3\text{ V}$, $V_{\text{NO}} = \text{Open}$, | Switch ON, see Figure 13 | 25°C Full | 3.6 V | | -2 0.3 | 2 ⁽²⁾ | nA | |
| | | | | | | | | -20 | | 20 |
| Digital Control Inputs (IN1, IN2)⁽³⁾ | | | | | | | | | | |
| V_{IH} | Input logic high | | | Full | | | 2 | 5.5 | V | |
| V_{IL} | Input logic low | | | Full | | | 0 | 0.8 | V | |
| $I_{\text{IH}}, I_{\text{IL}}$ | Input leakage current | $V_I = 5.5\text{ V or }0$ | | 25°C Full | 3.6 V | | -2 0.3 | 2 | nA | |
| | | | | | | | | -20 | | 20 |

- (1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
 (2) Not tested in production.
 (3) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

Electrical Characteristics: 3.3-V Supply (continued)

 $V_+ = 3\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT |
|----------------|------------------------------|---|--|-------|-------|-------|-------|-----|---------------|
| Dynamic | | | | | | | | | |
| Q_C | Charge injection | $V_{GEN} = 0$, $R_{GEN} = 0$, | $C_L = 1\text{ nF}$, see Figure 19 | 25°C | 5 V | | 6 | | pC |
| $C_{NO(OFF)}$ | NO OFF capacitance | $V_{NO} = V_+$ or GND, Switch OFF, | See Figure 14 | 25°C | 3.3 V | | 19.5 | | pF |
| $C_{COM(OFF)}$ | COM OFF capacitance | $V_{COM} = V_+$ or GND, Switch OFF, | See Figure 14 | 25°C | 3.3 V | | 18.5 | | pF |
| $C_{NO(ON)}$ | NO ON capacitance | $V_{NO} = V_+$ or GND, Switch ON, | See Figure 14 | 25°C | 3.3 V | | 36 | | pF |
| $C_{COM(ON)}$ | COM ON capacitance | $V_{COM} = V_+$ or GND, Switch ON, | See Figure 14 | 25°C | 3.3 V | | 36 | | pF |
| C_I | Digital input capacitance | $V_I = V_+$ or GND, | See Figure 14 | 25°C | 3.3 V | | 2 | | pF |
| BW | Bandwidth | $R_L = 50\ \Omega$, Switch ON, | See Figure 16 | 25°C | 3.3 V | | 150 | | MHz |
| O_{ISO} | OFF isolation | $R_L = 50\ \Omega$, $f = 1\text{ MHz}$, | Switch OFF, see Figure 17 | 25°C | 3.3 V | | -62 | | dB |
| X_{TALK} | Crosstalk | $R_L = 50\ \Omega$, $f = 1\text{ MHz}$, | Switch ON, see Figure 18 | 25°C | 3.3 V | | -85 | | dB |
| THD | Total harmonic distortion | $R_L = 600\ \Omega$, $C_L = 50\text{ pF}$, | $f = 20\text{ Hz to }20\text{ kHz}$, see Figure 20 | 25°C | 3.3 V | | 0.01% | | |
| Supply | | | | | | | | | |
| I_+ | Positive supply current | $V_I = V_+$ or GND, | Switch ON or OFF | 25°C | 3.6 V | 0.001 | 0.05 | 0.3 | μA |
| | | | | Full | | | | | |

6.7 Electrical Characteristics: 2.5-V Supply

 $V_+ = 2.3\text{ V to }2.7\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT |
|----------------------|--|--|------------------------------|-------|-------|-----|------|-------|------------------|
| Analog Switch | | | | | | | | | |
| V_{COM}, V_{NO} | Analog signal range | | | | | 0 | | V_+ | V |
| r_{peak} | Peak ON resistance | $0 \leq V_{NO} \leq V_+$, $I_{COM} = -8\text{ mA}$, | Switch ON, see Figure 11 | 25°C | 2.3 V | | 1.8 | 2.4 | Ω |
| | | | | Full | | | | | |
| r_{on} | ON-state resistance | $V_{NO} = 1.8\text{ V}$, $I_{COM} = -8\text{ mA}$, | Switch ON, see Figure 11 | 25°C | 2.3 V | | 1.2 | 2.1 | Ω |
| | | | | Full | | | | | |
| Δr_{on} | ON-state resistance match between channels | $V_{NO} = 1.8\text{ V}, 0.8\text{ V}$, $I_{COM} = -8\text{ mA}$, | Switch ON, see Figure 11 | 25°C | 2.3 V | | 0.04 | 0.15 | Ω |
| | | | | Full | | | | | |
| $r_{on(flat)}$ | ON-state resistance flatness | $0 \leq V_{NO} \leq V_+$, $I_{COM} = -8\text{ mA}$, | Switch ON, see Figure 11 | 25°C | 2.3 V | | 0.7 | | Ω |
| | | | | 25°C | | | | | |
| | | | | Full | | | | | |
| $I_{NO(OFF)}$ | NO OFF leakage current | $V_{NO} = 0.5\text{ V}$, $V_{COM} = 2.3\text{ V}$, or $V_{NO} = 2.3\text{ V}$, $V_{COM} = 0.5\text{ V}$, | Switch OFF, see Figure 12 | 25°C | 2.7 V | | -5 | 0.3 | 5 ⁽²⁾ |
| | | | | Full | | | | | |
| $I_{NO(PWROFF)}$ | | $V_{NO} = 0\text{ to }2.7\text{ V}$, $V_{COM} = 2.7\text{ V to }0$, | Switch OFF, see Figure 12 | 25°C | 0 V | | -2 | 0.05 | 2 ⁽²⁾ |
| | | | | Full | | | | | |

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

(2) Not tested in production.

Electrical Characteristics: 2.5-V Supply (continued)
 $V_+ = 2.3 \text{ V to } 2.7 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT |
|--|---------------------------|--|---|-------|-------|-----|-------|------------------|------|
| $I_{\text{COM(OFF)}}$ | COM OFF leakage current | $V_{\text{NO}} = 2.3 \text{ V}$, $V_{\text{COM}} = 0.5 \text{ V}$, or $V_{\text{NO}} = 0.5 \text{ V}$, $V_{\text{COM}} = 2.3 \text{ V}$, | Switch OFF, see Figure 12 | 25°C | 2.7 V | -5 | 0.3 | 5 ⁽²⁾ | nA |
| | | | | Full | | -50 | | 50 | |
| $I_{\text{COM(PWROFF)}}$ | | $V_{\text{COM}} = 0 \text{ to } 2.7 \text{ V}$, $V_{\text{NO}} = 2.7 \text{ V to } 0$, | Switch OFF, see Figure 12 | 25°C | 0 V | -2 | 0.05 | 2 ⁽²⁾ | μA |
| | | | | Full | | -15 | | 15 | |
| $I_{\text{NO(ON)}}$ | NO ON leakage current | $V_{\text{NO}} = 0.5 \text{ V}$, $V_{\text{COM}} = \text{Open}$, or $V_{\text{NO}} = 2.3 \text{ V}$, $V_{\text{COM}} = \text{Open}$, | Switch ON, see Figure 13 | 25°C | 2.7 V | -2 | 0.3 | 2 ⁽²⁾ | nA |
| | | | | Full | | -20 | | 20 | |
| $I_{\text{COM(ON)}}$ | COM ON leakage current | $V_{\text{COM}} = 0.5 \text{ V}$, $V_{\text{NO}} = \text{Open}$, or $V_{\text{COM}} = 2.3 \text{ V}$, $V_{\text{NO}} = \text{Open}$, | Switch ON, see Figure 13 | 25°C | 2.7 V | -2 | 0.3 | 2 ⁽²⁾ | nA |
| | | | | Full | | -20 | | 20 | |
| Digital Control Inputs (IN1, IN2) | | | | | | | | | |
| V_{IH} | Input logic high | | | Full | | 1.8 | | 5.5 | V |
| V_{IL} | Input logic low | | | Full | | 0 | | 0.6 | V |
| $I_{\text{IH}}, I_{\text{IL}}$ | Input leakage current | $V_I = 5.5 \text{ V or } 0$ | | 25°C | 2.7 V | -2 | 0.3 | 2 | nA |
| | | | | Full | | -20 | | 20 | |
| Dynamic | | | | | | | | | |
| Q_C | Charge injection | $V_{\text{GEN}} = 0$, $R_{\text{GEN}} = 0$, | $C_L = 1 \text{ nF}$, see Figure 19 | 25°C | 2.5 V | | 4 | | pC |
| $C_{\text{NO(OFF)}}$ | NO OFF capacitance | $V_{\text{NO}} = V_+ \text{ or GND}$, Switch OFF, | See Figure 14 | 25°C | 2.5 V | | 19.5 | | pF |
| $C_{\text{COM(OFF)}}$ | COM OFF capacitance | $V_{\text{COM}} = V_+ \text{ or GND}$, Switch OFF, | See Figure 14 | 25°C | 2.5 V | | 18.5 | | pF |
| $C_{\text{NO(ON)}}$ | NO ON capacitance | $V_{\text{NO}} = V_+ \text{ or GND}$, Switch ON, | See Figure 14 | 25°C | 2.5 V | | 36.5 | | pF |
| $C_{\text{COM(ON)}}$ | COM ON capacitance | $V_{\text{COM}} = V_+ \text{ or GND}$, Switch ON, | See Figure 14 | 25°C | 2.5 V | | 36.5 | | pF |
| C_I | Digital input capacitance | $V_I = V_+ \text{ or GND}$, | See Figure 14 | 25°C | 2.5 V | | 2 | | pF |
| BW | Bandwidth | $R_L = 50 \Omega$, Switch ON, | See Figure 16 | 25°C | 2.5 V | | 150 | | MHz |
| O_{ISO} | OFF isolation | $R_L = 50 \Omega$, $f = 1 \text{ MHz}$, | Switch OFF, see Figure 17 | 25°C | 2.5 V | | -62 | | dB |
| X_{TALK} | Crosstalk | $R_L = 50 \Omega$, $f = 1 \text{ MHz}$, | Switch ON, see Figure 18 | 25°C | 2.5 V | | -85 | | dB |
| THD | Total harmonic distortion | $R_L = 600 \Omega$, $C_L = 50 \text{ pF}$, | $f = 20 \text{ Hz to } 20 \text{ kHz}$, see Figure 20 | 25°C | 2.5 V | | 0.02% | | |
| Supply | | | | | | | | | |
| I_+ | Positive supply current | $V_I = V_+ \text{ or GND}$, | Switch ON or OFF | 25°C | 2.7 V | | 0.001 | 0.02 | μA |
| | | | | Full | | | | 0.25 | |

6.8 Electrical Characteristics: 1.8-V Supply

 $V_+ = 1.65 \text{ V to } 1.95 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT | |
|--|--|--|---|-------|--------|-----|------|-------|------------------|---------------|
| Analog Switch | | | | | | | | | | |
| V_{COM}, V_{NO} | Analog signal range | | | | | 0 | | V_+ | V | |
| r_{peak} | Peak ON resistance | $0 \leq V_{NO} \leq V_+$, $I_{COM} = -2 \text{ mA}$, | Switch ON, see Figure 11 | 25°C | 1.65 V | | 4.2 | 25 | Ω | |
| | | | | Full | | | 30 | | | |
| r_{on} | ON-state resistance | $V_{NO} = 0.6 \text{ V}, 1.5 \text{ V}$, $I_{COM} = -2 \text{ mA}$, | Switch ON, see Figure 11 | 25°C | 1.65 V | | 1.6 | 3.9 | Ω | |
| | | | | Full | | | 4 | | | |
| Δr_{on} | ON-state resistance match between channels | $V_{NO} = 1.5 \text{ V}$, $I_{COM} = -2 \text{ mA}$, | Switch ON, see Figure 11 | 25°C | 1.65 V | | 0.04 | 0.2 | Ω | |
| | | | | Full | | | 0.2 | | | |
| $r_{on(Flat)}$ | ON-state resistance flatness | $0 \leq V_{NO} \leq V_+$, $I_{COM} = -2 \text{ mA}$, | Switch ON, see Figure 11 | 25°C | 1.65 V | | 2.8 | | Ω | |
| | | | | 25°C | | | 4.1 | 22 | | |
| | | | | Full | | | | 27 | | |
| $I_{NO(OFF)}$ | NO OFF leakage current | $V_{NO} = 0.3 \text{ V}$, $V_{COM} = 1.65 \text{ V}$, or $V_{NO} = 1.65 \text{ V}$, $V_{COM} = 0.3 \text{ V}$, | Switch OFF, see Figure 12 | 25°C | 1.95 V | | -5 | 0.3 | 5 ⁽²⁾ | nA |
| | | | | Full | | | -50 | 50 | | |
| $I_{NO(PWROFF)}$ | | $V_{NO} = 0 \text{ to } 1.95 \text{ V}$, $V_{COM} = 1.95 \text{ V to } 0$, | Switch OFF, see Figure 12 | 25°C | 0 V | | -2 | 0.05 | 2 ⁽²⁾ | μA |
| | | | | Full | | | -10 | 10 | | |
| $I_{COM(OFF)}$ | COM OFF leakage current | $V_{NO} = 1.65 \text{ V}$, $V_{COM} = 0.3 \text{ V}$, or $V_{NO} = 0.3 \text{ V}$, $V_{COM} = 1.65 \text{ V}$, | Switch OFF, see Figure 12 | 25°C | 1.95 V | | -5 | 0.3 | 5 ⁽²⁾ | nA |
| | | | | Full | | | -50 | 50 | | |
| $I_{COM(PWROFF)}$ | | $V_{COM} = 0 \text{ to } 1.95 \text{ V}$, $V_{NO} = 1.95 \text{ V to } 0$, | Switch OFF, see Figure 12 | 25°C | 0 V | | -2 | 0.05 | 2 ⁽²⁾ | μA |
| | | | | Full | | | -10 | 10 | | |
| $I_{NO(ON)}$ | NO ON leakage current | $V_{NO} = 0.3 \text{ V}$, $V_{COM} = \text{Open}$, or $V_{NO} = 1.65 \text{ V}$, $V_{COM} = \text{Open}$, | Switch ON, see Figure 13 | 25°C | 1.95 V | | -2 | 0.3 | 2 ⁽²⁾ | nA |
| | | | | Full | | | -20 | 20 | | |
| $I_{COM(ON)}$ | COM ON leakage current | $V_{NO} = \text{Open}$, $V_{COM} = 0.3 \text{ V}$, or $V_{NO} = \text{Open}$, $V_{COM} = 1.65 \text{ V}$, | Switch ON, see Figure 13 | 25°C | 1.95 V | | -2 | 0.3 | 2 | nA |
| | | | | Full | | | -20 | 20 | | |
| Digital Control Inputs (IN1, IN2) | | | | | | | | | | |
| V_{IH} | Input logic high | | | Full | | 1.5 | | 5.5 | V | |
| V_{IL} | Input logic low | | | Full | | 0 | | 0.6 | V | |
| I_{IH}, I_{IL} | Input leakage current | $V_I = 5.5 \text{ V or } 0$ | | 25°C | 1.95 V | | -2 | 0.3 | 2 | μA |
| | | | | Full | | | -20 | 20 | | |
| Dynamic | | | | | | | | | | |
| Q_C | Charge injection | $V_{GEN} = 0$, $R_{GEN} = 0$, | $C_L = 1 \text{ nF}$, see Figure 19 | 25°C | 1.8 V | | 2 | | pC | |
| $C_{NO(OFF)}$ | NO OFF capacitance | $V_{NO} = V_+ \text{ or GND}$, Switch OFF, | See Figure 14 | 25°C | 1.8 V | | 19.5 | | pF | |
| $C_{COM(OFF)}$ | COM OFF capacitance | $V_{COM} = V_+ \text{ or GND}$, Switch OFF, | See Figure 14 | 25°C | 1.8 V | | 18.5 | | pF | |
| $C_{NO(ON)}$ | NO ON capacitance | $V_{NO} = V_+ \text{ or GND}$, Switch ON, | See Figure 14 | 25°C | 1.8 V | | 36.5 | | pF | |

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

(2) Not tested in production.

Electrical Characteristics: 1.8-V Supply (continued)

 $V_+ = 1.65\text{ V to }1.95\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT |
|----------------------|---------------------------|--|---|-------|--------|-----|--------|------|---------------|
| $C_{\text{COM(ON)}}$ | COM ON capacitance | $V_{\text{COM}} = V_+$ or GND, Switch ON, | See Figure 14 | 25°C | 1.8 V | | 36.5 | | pF |
| C_I | Digital input capacitance | $V_I = V_+$ or GND, | See Figure 14 | 25°C | 1.8 V | | 2 | | pF |
| BW | Bandwidth | $R_L = 50\ \Omega$, Switch ON, | See Figure 16 | 25°C | 1.8 V | | 150 | | MHz |
| O_{ISO} | OFF isolation | $R_L = 50\ \Omega$, $f = 1\text{ MHz}$, | Switch OFF, see Figure 17 | 25°C | 1.8 V | | -62 | | dB |
| THD | Total harmonic distortion | $R_L = 600\ \Omega$, $C_L = 50\text{ pF}$, | $f = 20\text{ Hz to }20\text{ kHz}$, see Figure 20 | 25°C | 1.8 V | | 0.055% | | |
| Supply | | | | | | | | | |
| I_+ | Positive supply current | $V_I = V_+$ or GND, | Switch ON or OFF | 25°C | 1.95 V | | 0.001 | 0.01 | μA |
| | | | | Full | | | | 0.15 | |

6.9 Switching Characteristics: 5-V Supply

 $V_+ = 4.5\text{ V to }5.5\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT |
|------------------|--------------|---|--|-------|----------------|-----|-----|-----|------|
| Dynamic | | | | | | | | | |
| t_{ON} | Turnon time | $V_{\text{COM}} = V_+$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, see Figure 15 | 25°C | 5 V | 1 | 4.5 | 7.5 | ns |
| | | | | Full | 4.5 V to 5.5 V | 1 | | 9 | |
| t_{OFF} | Turnoff time | $V_{\text{COM}} = V_+$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, see Figure 15 | 25°C | 5 V | 4.5 | 8 | 11 | ns |
| | | | | Full | 4.5 V to 5.5 V | 3.5 | | 13 | |

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

6.10 Switching Characteristics: 3.3-V Supply

 $V_+ = 3\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT |
|------------------|--------------|---|--|-------|--------------|-----|-----|------|------|
| Dynamic | | | | | | | | | |
| t_{ON} | Turnon time | $V_{\text{COM}} = V_+$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, see Figure 15 | 25°C | 3.3 V | 1.5 | 5 | 9.5 | ns |
| | | | | Full | 3 V to 3.6 V | 1 | | 10 | |
| t_{OFF} | Turnoff time | $V_{\text{COM}} = V_+$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, see Figure 15 | 25°C | 3.3 V | 4.5 | 8.5 | 11 | ns |
| | | | | Full | 3 V to 3.6 V | 3 | | 12.5 | |

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

6.11 Switching Characteristics: 2.5-V Supply

 $V_+ = 2.3\text{ V to }2.7\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT |
|------------------|--------------|---|--|-------|----------------|-----|-----|------|------|
| Dynamic | | | | | | | | | |
| t_{ON} | Turnon time | $V_{\text{COM}} = V_+$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, see Figure 15 | 25°C | 2.5 V | 2 | 6 | 10 | ns |
| | | | | Full | 2.3 V to 2.7 V | 1 | | 12 | |
| t_{OFF} | Turnoff time | $V_{\text{COM}} = V_+$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, see Figure 15 | 25°C | 2.5 V | 4.5 | 8 | 12.5 | ns |
| | | | | Full | 2.3 V to 2.7 V | 3 | | 15 | |

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

6.12 Switching Characteristics: 1.8-V Supply

 $V_+ = 1.65\text{ V to }1.95\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP | MAX | UNIT |
|----------------|--------------|---|---|-------|---------------------|-----|-----|------|------|
| Dynamic | | | | | | | | | |
| t_{ON} | Turnon time | $V_{COM} = V_+$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, see Figure 15 | 25°C | 1.8 V | 3 | 9 | 18 | ns |
| | | | | Full | 1.65 V to 1.95 V | 1 | | 20 | |
| t_{OFF} | Turnoff time | $V_{COM} = V_+$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, see Figure 15 | 25°C | 1.8 V | 5 | 10 | 15.5 | ns |
| | | | | Full | 1.65 V to 1.95 V | 4 | | 18.5 | |

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

6.13 Typical Characteristics

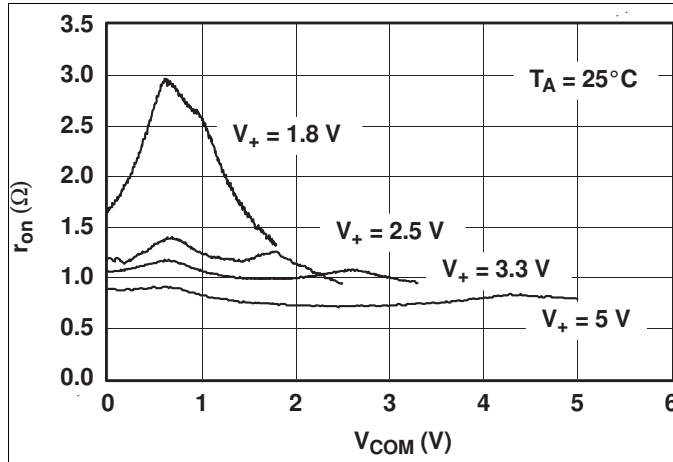


Figure 1. r_{on} vs V_{COM}

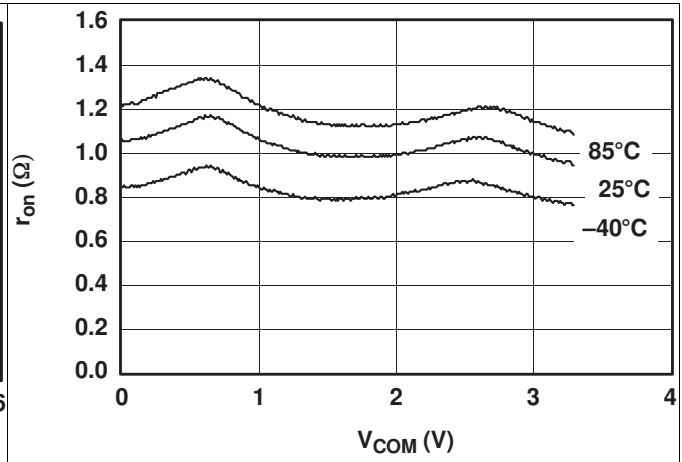


Figure 2. r_{on} vs V_{COM} ($V_+ = 3.3$ V)

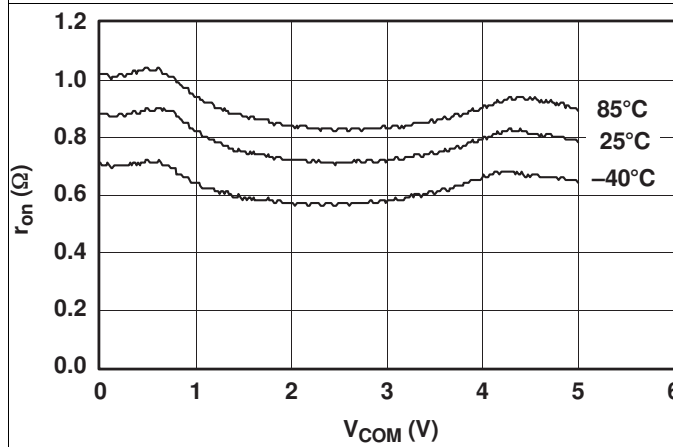


Figure 3. r_{on} vs V_{COM} ($V_+ = 5$ V)

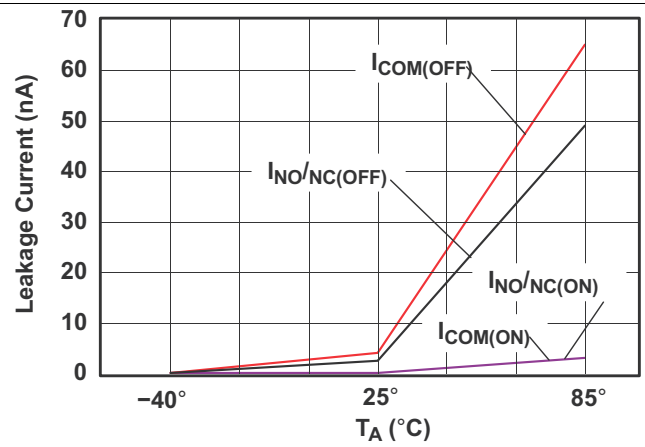


Figure 4. Leakage Current vs Temperature ($V_+ = 5.5$ V)

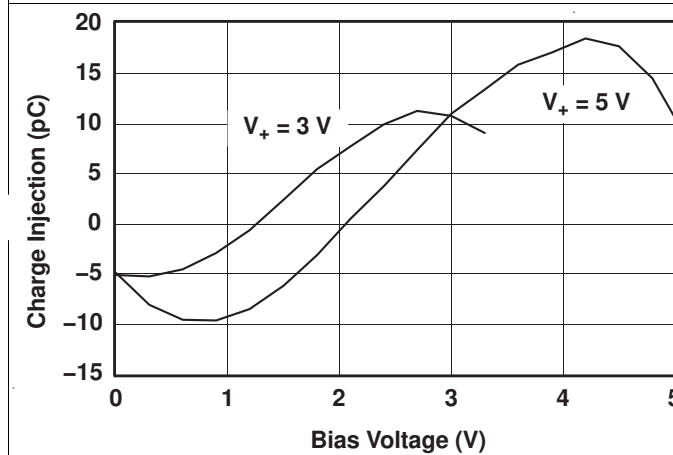


Figure 5. Charge Injection (Q_C) vs V_{COM}

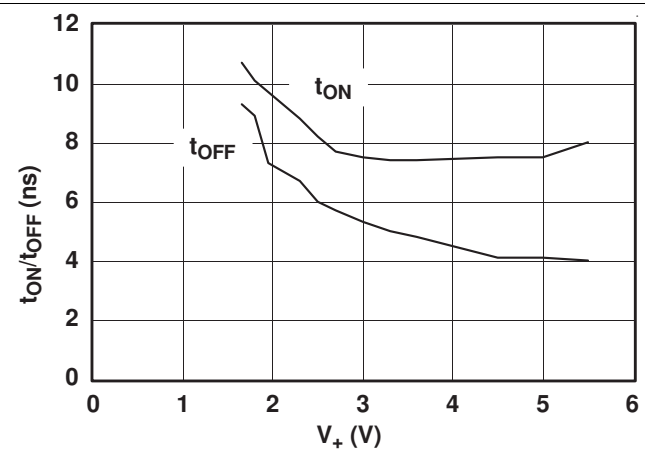


Figure 6. t_{ON} and t_{OFF} vs Supply Voltage

Typical Characteristics (continued)

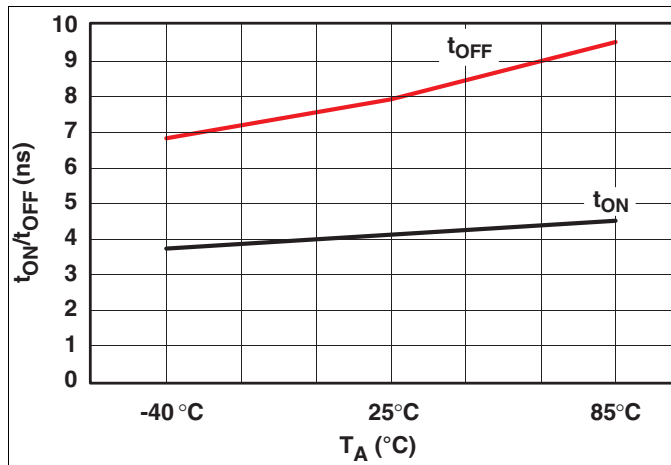


Figure 7. t_{ON} and t_{OFF} vs Temperature (V₊ = 5 V)

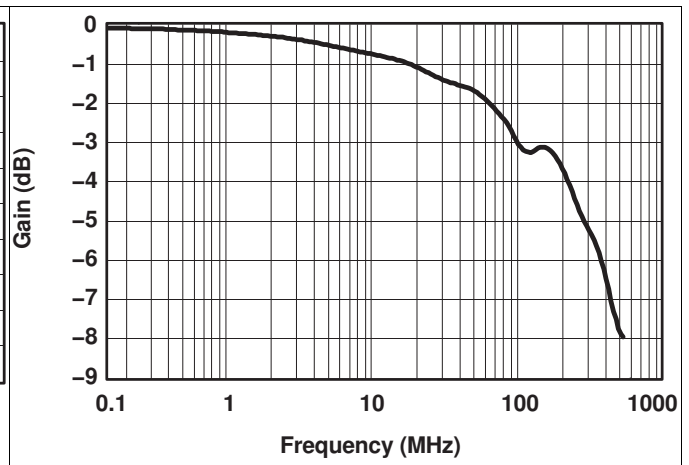


Figure 8. Bandwidth (V₊ = 5 V)

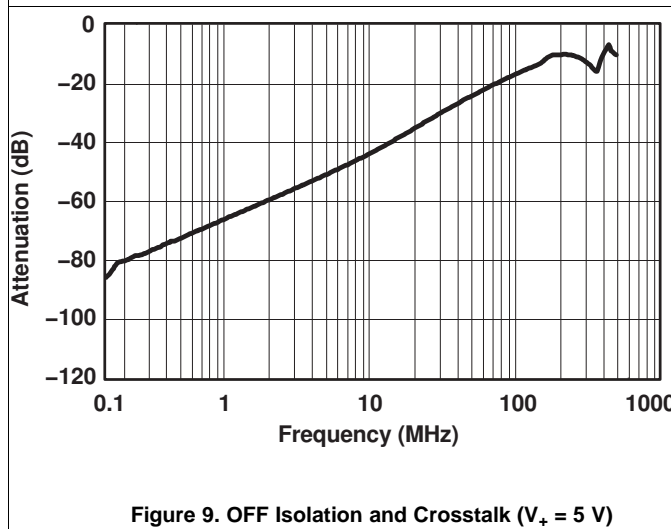


Figure 9. OFF Isolation and Crosstalk (V₊ = 5 V)

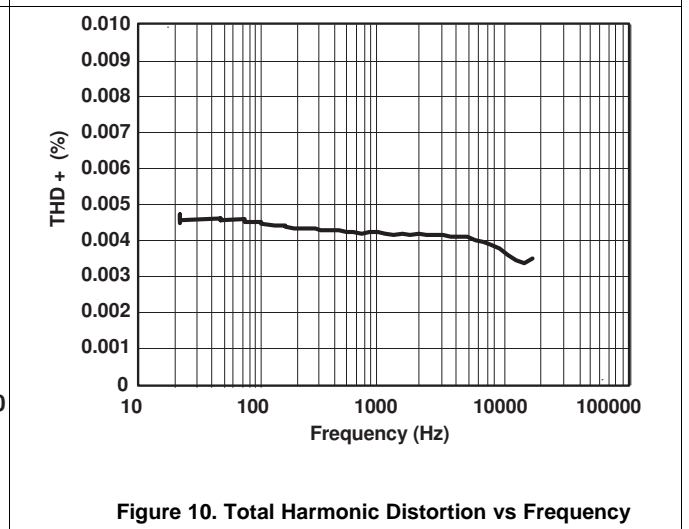


Figure 10. Total Harmonic Distortion vs Frequency

7 Parameter Measurement Information

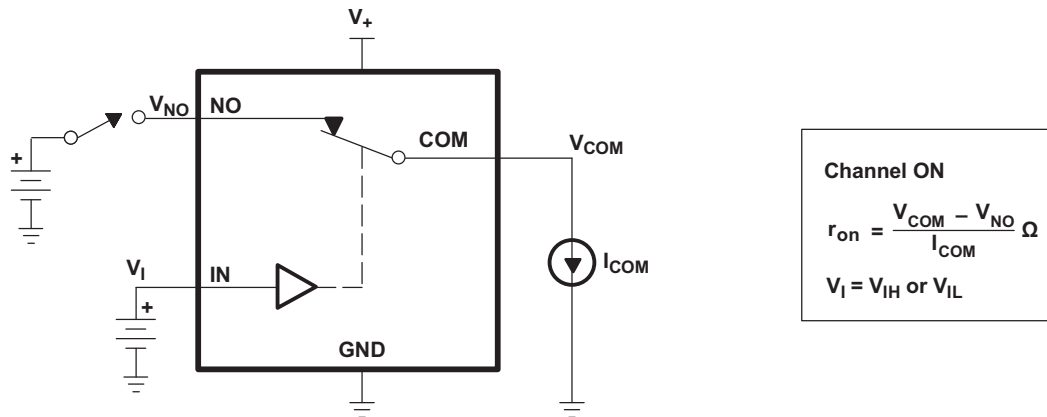


Figure 11. ON-State Resistance (r_{on})

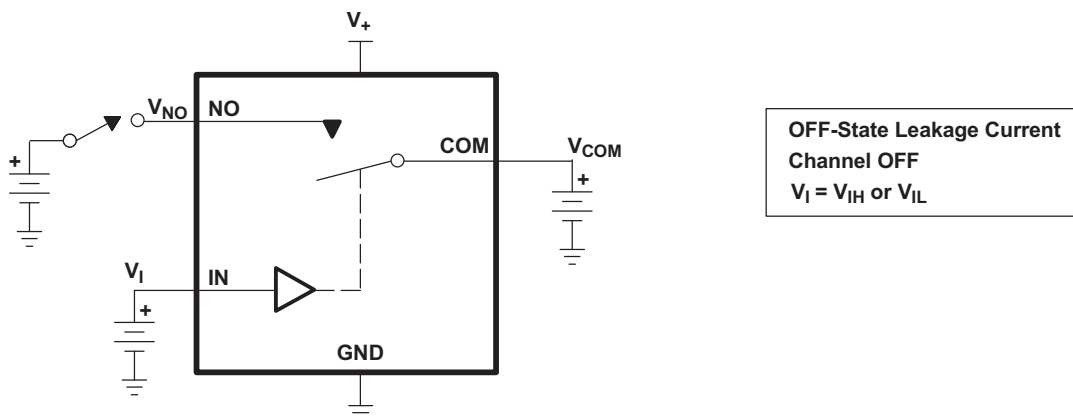


Figure 12. OFF-State Leakage Current ($I_{COM(OFF)}$, $I_{NC(OFF)}$, $I_{COM(PWROFF)}$, $I_{NC(PWR(F))}$)

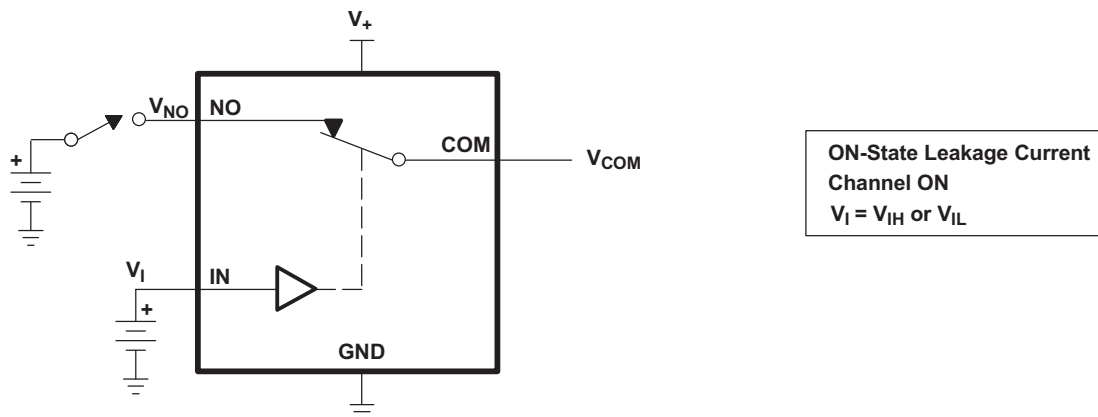


Figure 13. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$)

Parameter Measurement Information (continued)

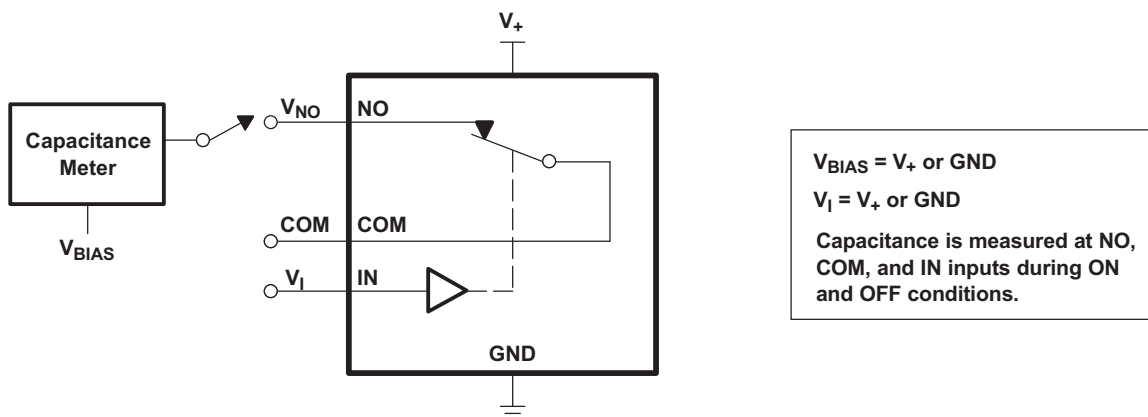
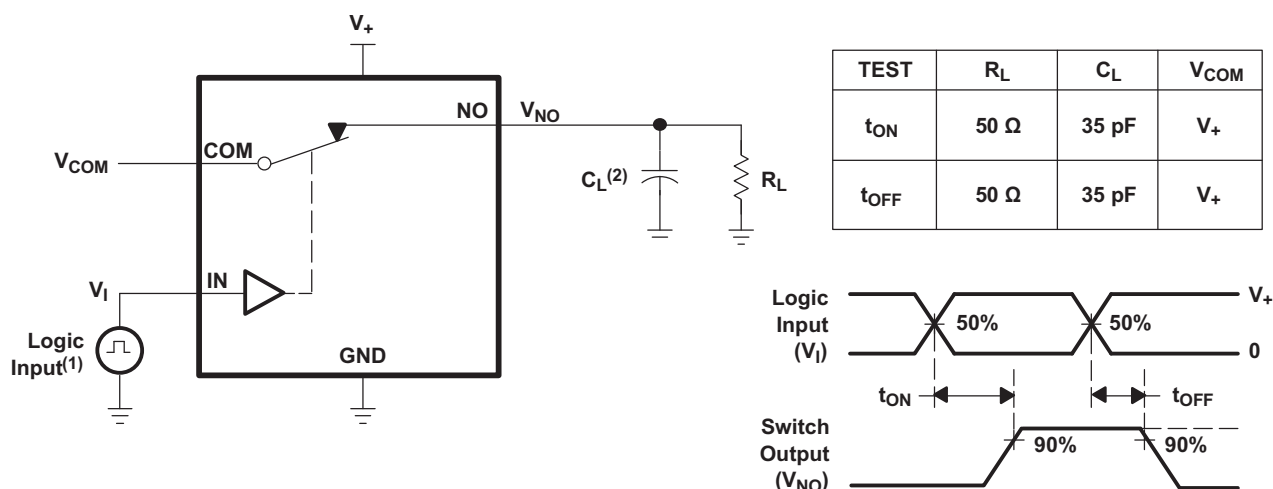


Figure 14. Capacitance (C_I , $C_{COM(OFF)}$, $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NC(ON)}$)



- (1) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r < 5$ ns, $t_f < 5$ ns.
- (2) C_L includes probe and jig capacitance.

Figure 15. Turnon (t_{ON}) and Turnoff Time (t_{OFF})

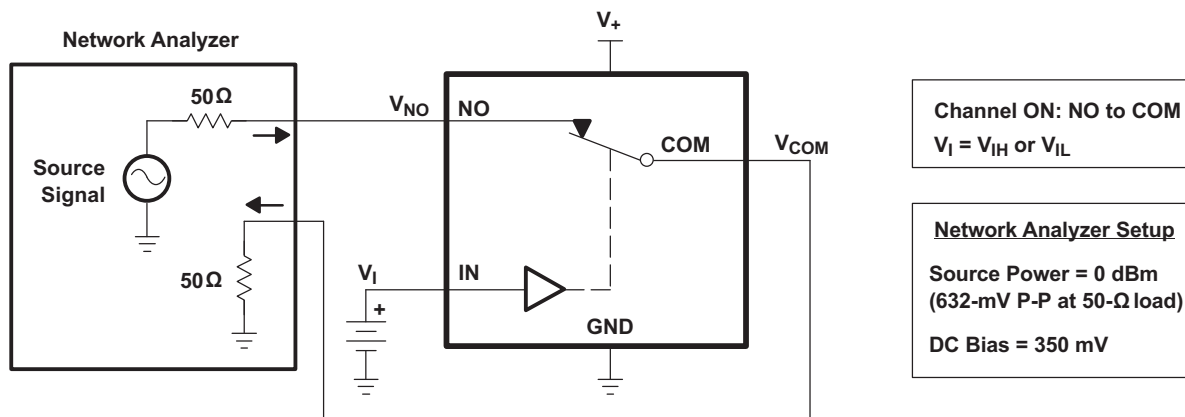


Figure 16. Bandwidth (BW)

Parameter Measurement Information (continued)

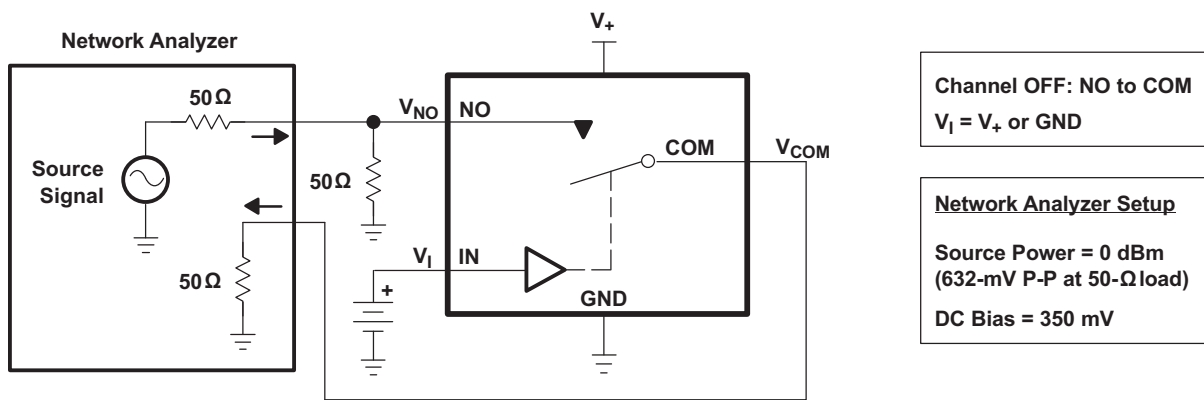


Figure 17. OFF Isolation (O_{ISO})

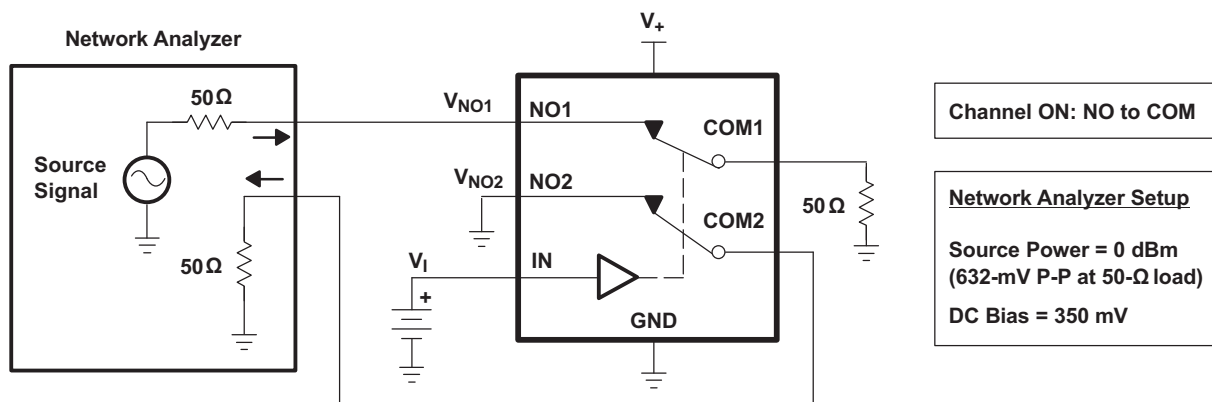
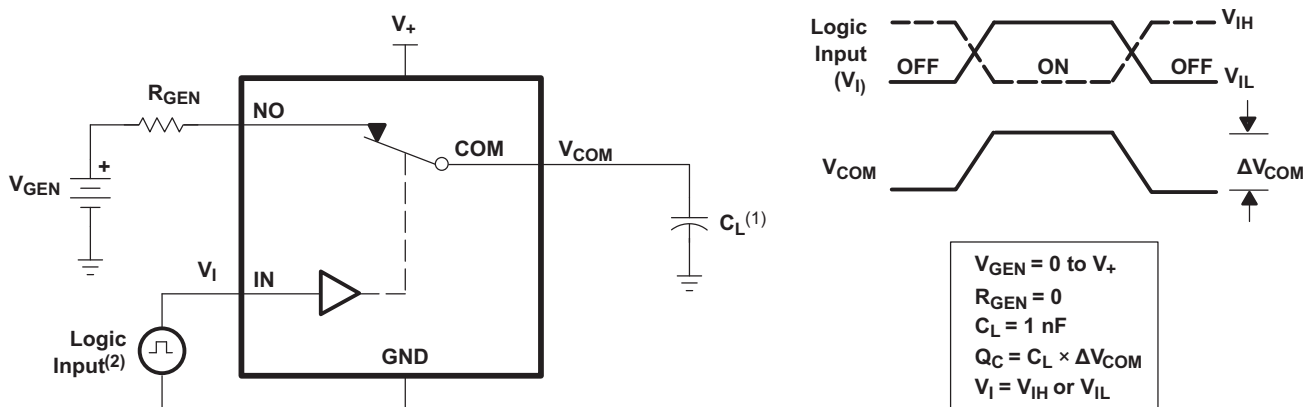


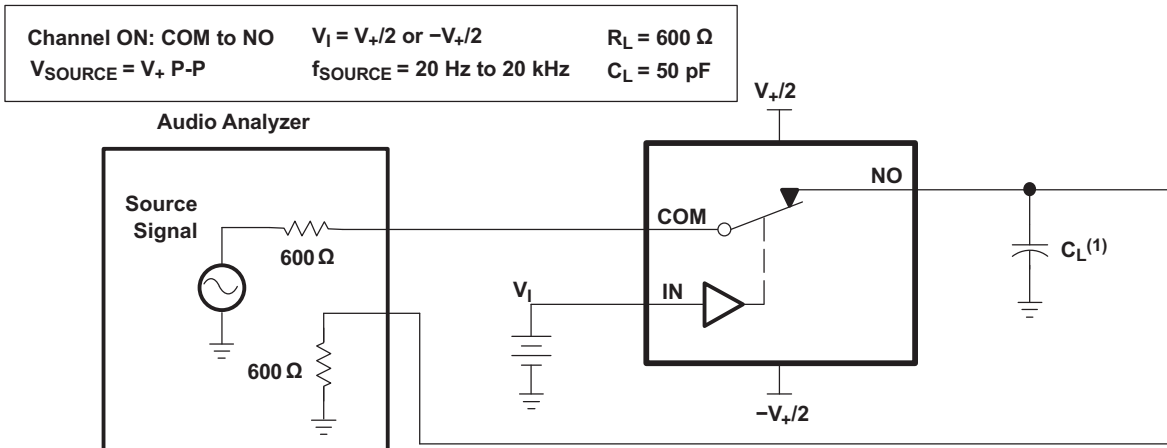
Figure 18. Crosstalk (X_{TALK})



- (1) C_L includes probe and jig capacitance.
- (2) All input pulses are supplied by generators having the following characteristics:
 $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.

Figure 19. Charge Injection (Q_C)

Parameter Measurement Information (continued)



(1) C_L includes probe and jig capacitance.

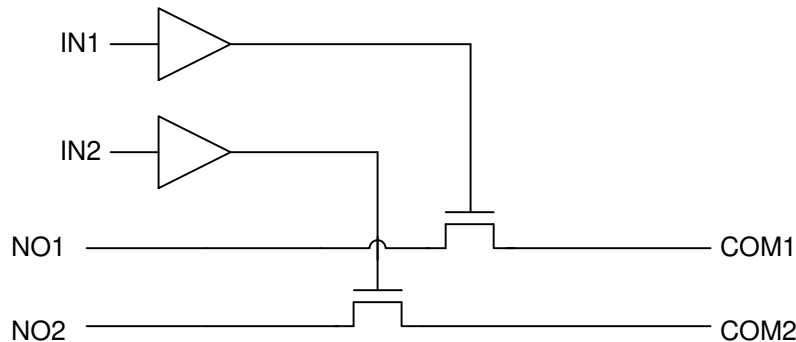
Figure 20. Total Harmonic Distortion (THD)

8 Detailed Description

8.1 Overview

The TS5A23166 is a dual single-pole single-throw (SPST) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers a low ON-state resistance. The device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications. [Table 2](#) shows the descriptions of each parameter specified in the datasheet.

8.2 Functional Block Diagram



8.3 Feature Description

Tolerant control inputs allow 5-V logic levels to be present on the IN pin at any value of V_{CC} . Low ON-resistance allows minimal signal distortion through device.

8.4 Device Functional Modes

[Table 1](#) shows the functional modes for TS5A23166.

Table 1. Function Table

| IN | NO TO COM, COM TO NO |
|----|-------------------------|
| L | OFF |
| H | ON |

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TS5A23166 dual SPST analog switch is a basic component that could be used in any electrical system design. One example application is a gain selector, which is described in the *Typical Application* section.

9.2 Typical Application

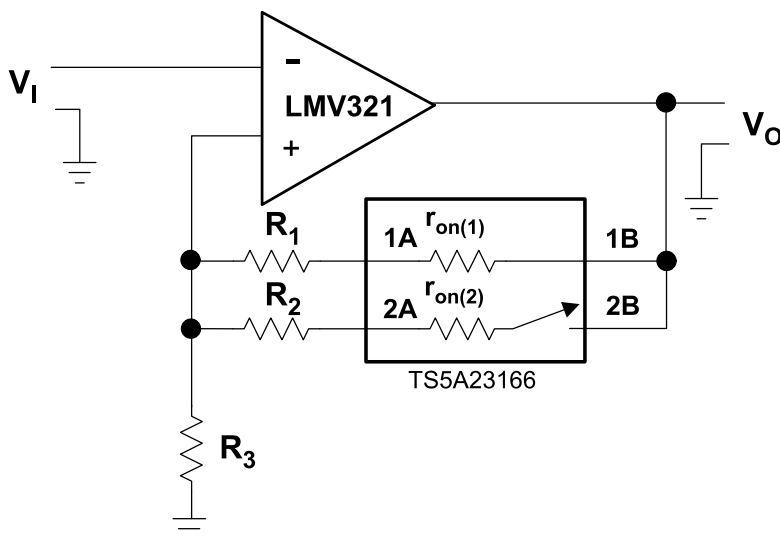


Figure 21. Gain-Control Circuit for OP Amplifier

9.2.1 Design Requirements

By selecting values of R₁ and R₂, such that R_x >> r_{on(x)}, r_{on} of TS5A23166 can be ignored. The gain of op amp can be calculated as follow:

$$V_o / V_i = 1 + R_{||} / R_3 \quad (1)$$

$$R_{||} = (R_1 + r_{on(1)}) || (R_2 + r_{on(2)}) \quad (2)$$

9.2.2 Detailed Design Procedure

Place a switch in series with the input of the op amp. Because the op amp input impedance is very large, a switch on r_{on(1)} is irrelevant.

Typical Application (continued)

9.2.3 Application Curve

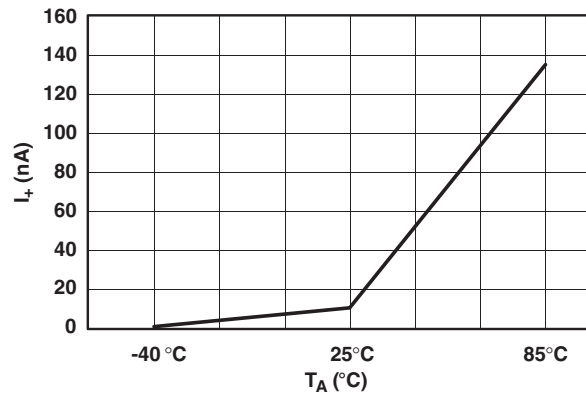


Figure 22. Power-Supply Current vs Temperature (V₊ = 5 V)

10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the [Recommended Operating Conditions](#).

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1-μF bypass capacitor is recommended. If there are multiple pins labeled V_{CC}, then a 0.01-μF or 0.022-μF capacitor is recommended for each V_{CC} because the VCC pins will be tied together internally. For devices with dual supply pins operating at different voltages, for example V_{CC} and V_{DD}, a 0.1-μF bypass capacitor is recommended for each supply pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1-μF and 1-μF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

11 Layout

11.1 Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a 90° angle, a reflection can occur. This is primarily due to the change of width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This upsets the transmission line characteristics, especially the distributed capacitance and self-inductance of the trace — resulting in the reflection. It is a given that not all PCB traces can be straight, and so they will have to turn corners. [Figure 23](#) shows progressively better techniques of rounding corners. Only the last example maintains constant trace width and minimizes reflections.

11.2 Layout Example

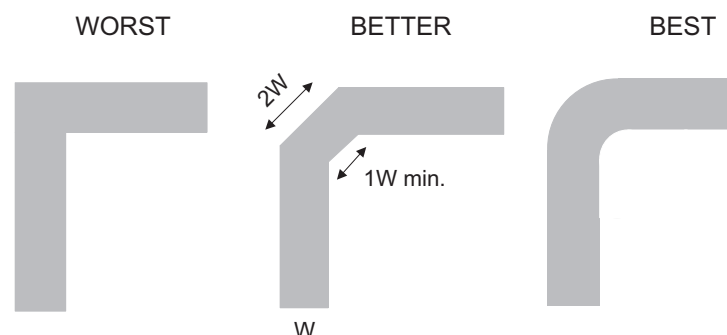


Figure 23. Trace Example

12 Device and Documentation Support

12.1 Device Support

12.1.1 Device Nomenclature

Table 2. Parameter Description

| SYMBOL | DESCRIPTION |
|-------------------|---|
| V_{COM} | Voltage at COM |
| V_{NO} | Voltage at NO |
| r_{on} | Resistance between COM and NO ports when the channel is ON |
| r_{peak} | Peak on-state resistance over a specified voltage range |
| $r_{on(Flat)}$ | Difference between the maximum and minimum value of r_{on} in a channel over the specified range of conditions |
| $I_{NO(OFF)}$ | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF-state under worst-case input and output conditions |
| $I_{NO(PWROFF)}$ | Leakage current measured at the NO port during the power-down condition, $V_+ = 0$ |
| $I_{COM(OFF)}$ | Leakage current measured at the COM port, with the corresponding channel (COM to NO) in the OFF-state under worst-case input and output conditions |
| $I_{COM(PWROFF)}$ | Leakage current measured at the COM port during the power-down condition, $V_+ = 0$ |
| $I_{NO(ON)}$ | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON-state and the output (COM) open |
| $I_{COM(ON)}$ | Leakage current measured at the COM port, with the corresponding channel (COM to NO) in the ON-state and the output (NO) open |
| V_{IH} | Minimum input voltage for logic high for the control input (IN) |
| V_{IL} | Maximum input voltage for logic low for the control input (IN) |
| V_I | Voltage at the control input (IN) |
| I_{IH}, I_{IL} | Leakage current measured at the control input (IN) |
| t_{ON} | Turnon time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning ON. |
| t_{OFF} | Turnoff time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning OFF. |
| Q_C | Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NO or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$. C_L is the load capacitance, and ΔV_{COM} is the change in analog output voltage. |
| $C_{NO(OFF)}$ | Capacitance at the NO port when the corresponding channel (NO to COM) is OFF |
| $C_{COM(OFF)}$ | Capacitance at the COM port when the corresponding channel (COM to NO) is OFF |
| $C_{NO(ON)}$ | Capacitance at the NO port when the corresponding channel (NO to COM) is ON |
| $C_{COM(ON)}$ | Capacitance at the COM port when the corresponding channel (COM to NO) is ON |
| C_I | Capacitance of control input (IN) |
| O_{ISO} | OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NO to COM) in the OFF state. |
| BW | Bandwidth of the switch. This is the frequency in which the gain of an ON channel is –3 dB below the DC gain. |
| THD | Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic. |
| I_+ | Static power-supply current with the control (IN) pin at V_+ or GND |

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Community Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

12.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| TS5A23166DCUR | ACTIVE | VSSOP | DCU | 8 | 3000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 85 | (AM, JAMQ, JAMR) JZ | Samples |
| TS5A23166DCURG4 | ACTIVE | VSSOP | DCU | 8 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | JAMR | Samples |
| TS5A23166YZPR | ACTIVE | DSBGA | YZP | 8 | 3000 | RoHS & Green | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | JMN | Samples |
| TS5A23166YZTR | ACTIVE | DSBGA | YZT | 8 | 3000 | RoHS & Green | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | JMN | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

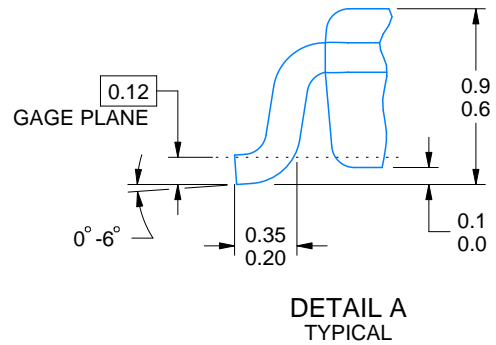
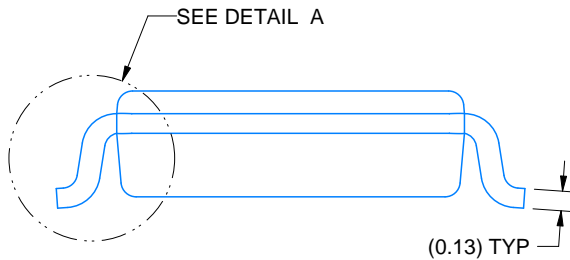
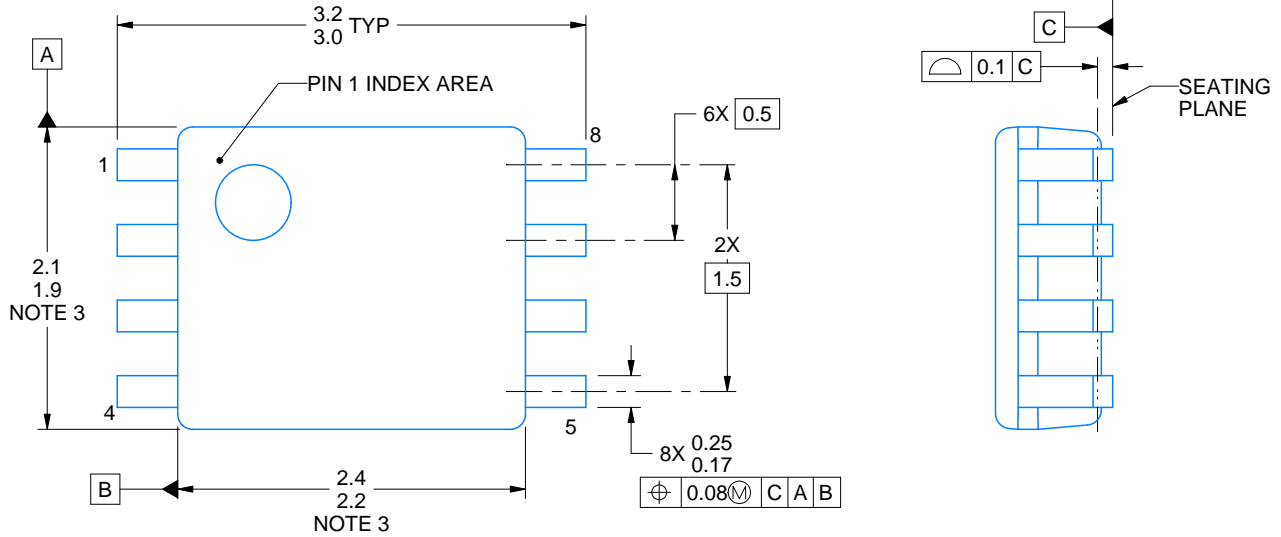
| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TS5A23166DCUR | VSSOP | DCU | 8 | 3000 | 178.0 | 9.5 | 2.25 | 3.35 | 1.05 | 4.0 | 8.0 | Q3 |
| TS5A23166DCUR | VSSOP | DCU | 8 | 3000 | 180.0 | 9.0 | 2.25 | 3.4 | 1.0 | 4.0 | 8.0 | Q3 |
| TS5A23166DCUR | VSSOP | DCU | 8 | 3000 | 180.0 | 8.4 | 2.25 | 3.35 | 1.05 | 4.0 | 8.0 | Q3 |
| TS5A23166DCURG4 | VSSOP | DCU | 8 | 3000 | 180.0 | 8.4 | 2.25 | 3.35 | 1.05 | 4.0 | 8.0 | Q3 |
| TS5A23166YZTR | DSBGA | YZT | 8 | 3000 | 178.0 | 9.2 | 1.02 | 2.02 | 0.75 | 4.0 | 8.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TS5A23166DCUR | VSSOP | DCU | 8 | 3000 | 202.0 | 201.0 | 28.0 |
| TS5A23166DCUR | VSSOP | DCU | 8 | 3000 | 182.0 | 182.0 | 20.0 |
| TS5A23166DCUR | VSSOP | DCU | 8 | 3000 | 202.0 | 201.0 | 28.0 |
| TS5A23166DCURG4 | VSSOP | DCU | 8 | 3000 | 202.0 | 201.0 | 28.0 |
| TS5A23166YZTR | DSBGA | YZT | 8 | 3000 | 220.0 | 220.0 | 35.0 |



4225266/A 09/2014

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-187 variation CA.

EXAMPLE BOARD LAYOUT

DCU0008A

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 25X



4225266/A 09/2014

NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCU0008A

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 25X

4225266/A 09/2014

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

YZP0008



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



4223082/A 07/2016

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

YZP0008

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
SCALE:40X



SOLDER MASK DETAILS
NOT TO SCALE

4223082/A 07/2016

NOTES: (continued)

- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).

EXAMPLE STENCIL DESIGN

YZP0008

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:40X

4223082/A 07/2016

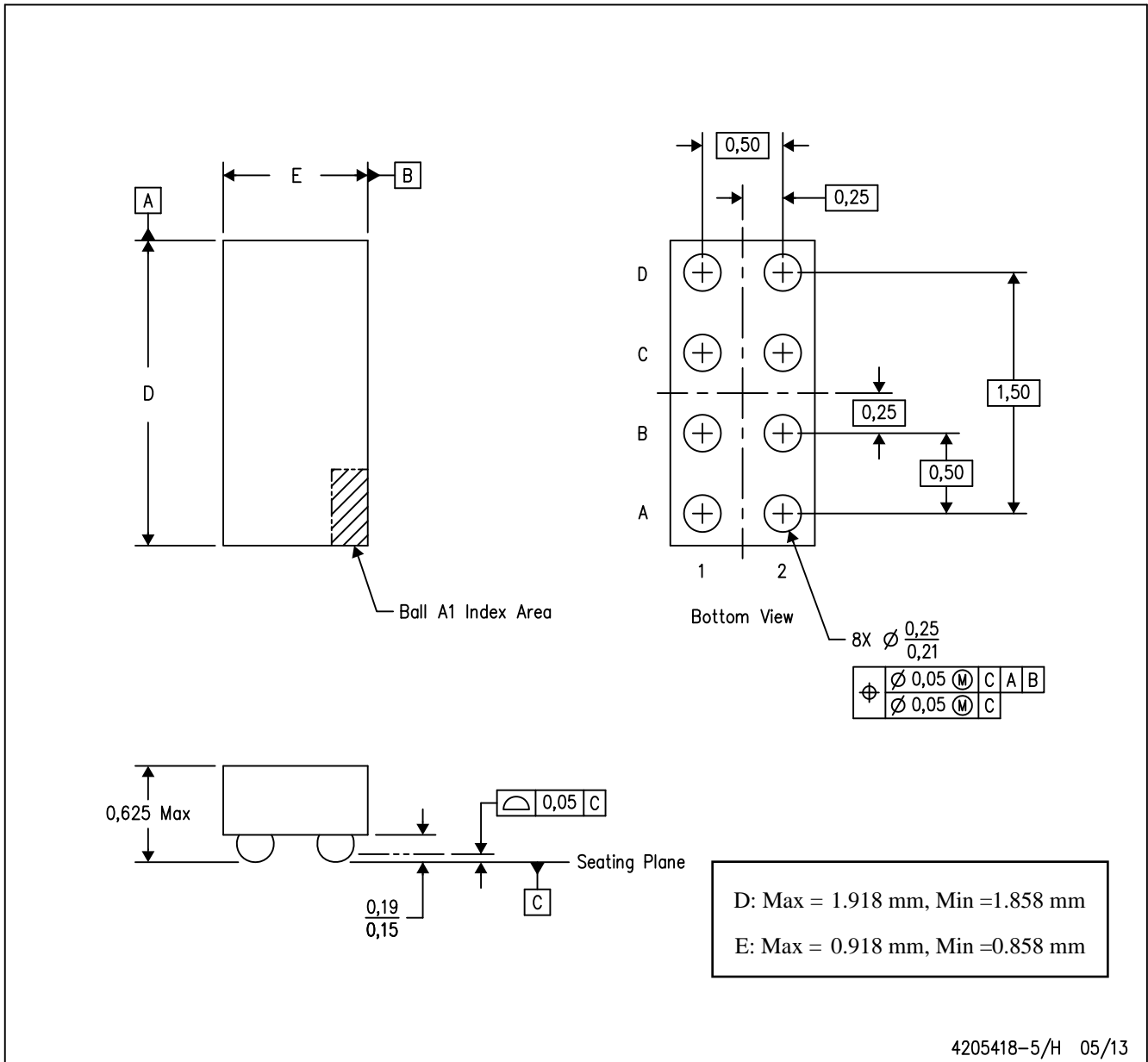
NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

MECHANICAL DATA

YZT (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2024, Texas Instruments Incorporated